

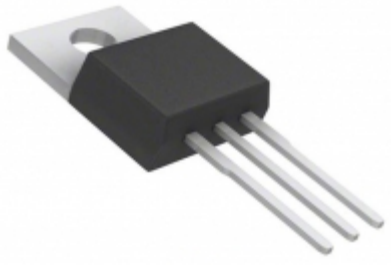


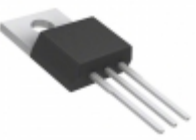
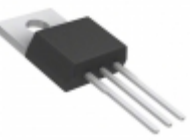



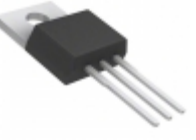
	<h2 style="color: red;">FQP6N50C</h2>
	<p><b>Hersteller-Teilenummer:</b> FQP6N50C</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 500V 5.5A TO-220</p> <p><b>Datenblätter:</b>  1.FQP6N50C.pdf  2.FQP6N50C.pdf</p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32365 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQP6N50C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 500V 5.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32365 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	98W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	5.5A (Tc)
Rds On (Max) @ Id, Vgs	1.2 Ohm @ 2.8A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	700pF @ 25V
Verpackung	Tube



















































FQP6N50C ist neu im Original, Suche FQP6N50C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP6N50C Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQP6N50C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FQP6N60</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 6.2A TO-220</p>	 <p><b>FQP6N60C_F080</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 5.5A TO-220</p>	 <p><b>FQP6N40CF</b> Fairchild/ON Semiconductor MOSFET N-CH 400V 6A TO-220</p>	 <p><b>FQP6N60C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 5.5A TO-220</p>
 <p><b>FQP6N50C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 5.5A TO-220</p>	 <p><b>FQP6N50</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 5.5A TO-220</p>	 <p><b>FQP6N50</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 5.5A TO-220</p>	 <p><b>FQP6N60</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 6.2A TO-220</p>

### heiße Teile

Mehr

 FQP50N06	 FQP50N06L	 FQP50N06L	 FQP50N08	 FQP55N06
 FQP55N06	 FQP55N10	 FQP55N10	 FQP58N08	 FQP58N08
 FQP5N20L	 FQP5N20L	 FQP5N50C	 FQP5N50C	 FQP5N60C
 FQP5N60C	 FQP630TSTU	 FQP630TSTU	 FQP65N06	 FQP65N06
 FQP6N40C	 FQP6N40C	 FQP6N40CF	 FQP6N40CF	 FQP6N50C
 FQP6N60C	 FQP6N60C	 FQP6N80C	 FQP6N80C	 FQP6N90C
 FQP6N90C	 FQP70N03L	 FQP70N06	 FQP70N06C	 FQP70N08
 FQP70N08	 FQP70N10	 FQP70N10	 FQP7N10L	 FQP7N10L
 FQP7N20L	 FQP7N20L	 FQP7N60C	 FQP7N65C	 FQP7N65C
 FQP7N80C	 FQP7N80C	 FQP85N06	 FQP85N06	 FQP8N50C

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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